

IN THE CLAIMS:

1. (Amended) A semiconductor device comprising:

- (a) a rigid substrate, formed by glass fibers impregnated with epoxy resin, having a first main surface and a second main surface opposite to the first main surface;
- (b) a semiconductor pellet mounted on the first main surface of the rigid substrate, the semiconductor pellet having a plurality of semiconductor circuit elements and a plurality of bonding pads;
- (c) a plurality of electrode pads formed on the second main surface of the rigid substrate; and
- (d) a plurality of bonding wires for electrically connecting the bonding pads of the semiconductor pellet with the electrode pads;

wherein the semiconductor pellet is mounted facedown on the rigid substrate, the rigid substrate has slits that extend from the first main surface to the second main surface and expose the bonding pads of the semiconductor pellet, the bonding wires extend through the slits in the rigid substrate to connect the bonding pads and the electrode pads, and bump electrodes are formed on said electrode pads.

7. (Canceled)

9. (Amended) A method of manufacturing a semiconductor device according to claim [9,] 8, further comprising a step of forming by transfer molding a resin sealing body that covers the periphery of the main surface of the rigid base substrate and seals the bonding wires, after the step of electrically connecting the bonding wires.

10. (Twice Amended) A semiconductor device [according to claim 10,] comprising:

- (a) a rigid substrate having a first main surface and a second main surface opposite to the first main surface;
- (b) a semiconductor pellet mounted on the first main surface of the rigid substrate, the semiconductor pellet having a plurality of semiconductor circuit elements and a plurality of bonding pads;
- (c) a plurality of electrode pads formed on the second main surface of the rigid substrate; and
- (d) a plurality of bonding wires for electrically connecting the bonding pads of the semiconductor pellet with the electrode pads;

wherein the semiconductor pellet is mounted facedown on the rigid substrate, the rigid substrate has slits that extend from the first main surface to the second main surface and expose the bonding pads of the semiconductor pellet, the bonding wires extend through the slits in the rigid substrate to connect the bonding pads and the electrode pads, and bump electrodes are formed on said electrode pads;

wherein said rigid substrate is formed by glass fibers impregnated with polyimide resin.

11. (Amended) A semiconductor device comprising:

- (a) a rigid substrate, formed by glass fibers impregnated with epoxy resin, having a first main surface and a second main surface opposite to the first main surface;
- (b) a semiconductor pellet mounted on the first main surface of the rigid substrate, the semiconductor pellet having a plurality of semiconductor circuit elements and a plurality of bonding pads;
- (c) a plurality of electrode pads formed on the second main surface of the rigid substrate; and
- (d) a plurality of bonding wires for electrically connecting the bonding pads of the semiconductor pellet with the electrode pads;

wherein the semiconductor pellet is mounted facedown on the rigid substrate, the rigid substrate has slits that extend from the first main surface to the second main surface and expose the bonding pads of the semiconductor pellet, and the bonding wires extend through the slits in the rigid substrate to connect the bonding pads and the electrode pads;

wherein the bonding pads are arranged at the periphery of the semiconductor pellet and the slits are formed along the directions of rows of the bonding pads.

14. (Amended) A semiconductor device comprising:

a substrate, formed by glass fibers impregnated with epoxy resin, of a quadrilateral shape having a first pair of opposed edges and a second pair of opposed edges, said substrate having a first main surface, a second main surface opposite to said first main surface and a first slit and a second slit each extending from said first main surface to said second main surface, said first slit extending along one of said first pair of opposed edges, said second slit extending along the other of said first pair of opposed edges, said substrate having first electrode pads on said second main surface in a first area between said first and second slits, second electrode pads on said second main surface in a second area between said first slit and said one of the first pair of opposed edges, and third electrode pads on said second main surface in a third area between said second slit and the other of the first pair of opposed edges;

a semiconductor pellet having a main surface with semiconductor elements and bonding pads said semiconductor pellet being mounted on said first main surface of substrate such that said bonding pads are arranged to be in line with said first and second slits;

bonding wires extending through said first and second slits in said substrate and electrically connecting said bonding pads and said first to third electrode pads, respectively;

a resin member sealing said semiconductor pellet and said bonding wires; and

bump electrodes arranged on said second main surface of said substrate in said first to third areas in a direction of said first pair of opposed edges and being electrically connected with said first to third electrode pads, wherein said bump electrodes in said second and third areas are arranged to form plural rows in a direction of at least one of said second pair of opposed edges, respectively.

22. (Amended) A semiconductor device comprising:

a substrate, formed by glass fibers impregnated with epoxy resin, of a quadrilateral shape having first to fourth edges, said substrate having a first main surface, a second main surface opposite to said first main surface and first to fourth slits extending from said first main surface to said second main surface, said first to fourth slits respectively extending along said first to fourth edges and defining a first area of said substrate surrounded by said first to fourth slits and a second area of said substrate extending outside said first to fourth slits, said substrate having first electrode pads on said second main surface in said first area and second electrode pads on said second main surface in said second area;

a semiconductor pellet having a main surface with semiconductor elements and bonding pads, said semiconductor pellet being mounted on said first main surface of substrate such that said bonding pads are arranged in line with said first to fourth slits;

bonding wires extending through said first to fourth slits in said substrate and electrically connecting said bonding pads and said first and second electrode pads, respectively;

a resin member sealing said semiconductor pellet and said bonding wires; and bump electrodes arranged on said second main surface of said substrate in said first and second areas and being electrically connected with said first and second electrode pads,

wherein said bump electrodes in said second area are arranged to form a plurality of rows such that said plurality of rows are formed relative to one another to surround said first area of substrate.

26. (Twice Amended) A semiconductor device comprising:

(1) a semiconductor pellet of a quadrilateral shape having bonding pads formed in a main surface thereof, said semiconductor pellet having a first pair of opposed edges extending in a first direction and a second pair of opposed edges extending in a second direction which intersects said first direction, said bonding pads being arranged in said first direction to form a row of bonding pads;

(2) a substrate, formed by glass fibers impregnated with epoxy resin, having a first surface, a second surface opposite to said first surface, electrode pads formed on said second surface and a slit passing through said substrate from said first surface to said second surface and extending in said first direction, said semiconductor pellet being disposed on said first surface of said

substrate such that said main surface of said semiconductor pellet is faced to said first surface of said substrate and said row of bonding pads is arranged in said slit in a plane view, said electrode pads including first electrode pads arranged at one side of said slit and second electrode pads arranged at the other side of said slit in said second direction;

- (3) bonding wires, each extending from one of said bonding pads of said semiconductor pellet to pass through said slit from said first surface of the substrate to the second surface of the substrate to electrically connecting said electrode pads of said substrate with said bonding pads of said semiconductor pellet via said slit, said bonding wires including first bonding wires connected to said first electrode pads and second bonding wires connected to said second electrode pads;
- (4) bump electrodes being disposed on said second surface of said substrate and being electrically connected to said electrode pads of said substrate, said bump electrodes including first bump electrodes electrically connected to said first electrode pads and arranged at said one side of said slit and second bump electrodes electrically connected to said second electrode pads and arranged at the other side of said slit, said first and second bump electrodes being arranged to overlap with said semiconductor pellet in said plane view respectively; and
- (5) a resin sealing body sealing said bonding wires and said main surface of said semiconductor pellet exposed from said slit.

31. (Canceled)

39.-90. (Canceled)

91. (New) A semiconductor device comprising:

- (1) a semiconductor pellet of a quadrilateral shape having bonding pads formed in a main surface thereof, said semiconductor pellet having a first pair of opposed edges extending in a first direction and a second pair of opposed edges extending in a second direction which intersects said first direction, said bonding pads being arranged in said first direction to form a row of bonding pads;
- (2) a substrate, formed of a glass fiber impregnated with resin, having a first surface, a second surface opposite to said first surface, electrode pads formed on said second surface and a slit passing through said substrate from said first surface to said second surface and extending in said first direction, said semiconductor pellet being disposed on said first surface of said substrate such that said main surface of said semiconductor pellet is faced to said first surface of said substrate and said row of binding pads is arranged in said slit in a plane view, said electrode pads including first electrode pads arranged at one side of said slit and second electrode pads arranged at the other side of said slit in said second direction;
- (3) bonding wires electrically connecting said electrode pads of said substrate with said bonding pads of said semiconductor pellet via said slit, said bonding

wires including first bonding wires connected to said first electrode pads and second bonding wires connected to said second electrode pads;

(4) bump electrodes being disposed on said second surface of said substrate and being electrically connected to said electrode pads of said substrate, said bump electrodes including first bump electrodes electrically connected to said first electrode pads and arranged at said one side of said slit and second bump electrodes electrically connected to said second electrode pads and arranged at the other side of said slit, said first and second bump electrodes being arranged to overlap with said semiconductor pellet in said plane view respectively; and

(5) a resin sealing body sealing said bonding wires and said main surface of said semiconductor pellet exposed from said slit.

92. (New) A semiconductor device according to claim 91, wherein said row of bonding pads is disposed at a substantially central area between said first pair of opposed edges of said semiconductor pellet.

93. (New) A semiconductor device according to claim 92, wherein said semiconductor pellet has a rectangular shape, and wherein said first pair of opposed edges are corresponding to a pair of longer edges and said second pair of opposed edges are corresponding to a pair of shorter edges.

94. (New) A semiconductor device according to claim 91, wherein said slit is tapered so that opening on said second surface of substrate is greater than opening on said first surface of said substrate.

95. (New) A semiconductor device according to claim 91, wherein said bump electrodes are formed of a Pb-Sn alloy.

96. (New) A semiconductor device comprising:

- (1) a semiconductor pellet of a quadrilateral shape having bonding pads formed in a main surface thereof, said semiconductor pellet having a first pair of opposed edges extending in a first direction and a second pair of opposed edges extending in a second direction which intersects said first direction, said bonding pads being arranged in said first direction;
- (2) a substrate, formed of a glass fiber impregnated with resin, having a first surface, a second surface opposite to said first surface, electrode pads formed on said second surface and a slit passing through said substrate from said first surface to said second surface and extending in said first direction, said semiconductor pellet being disposed on said first surface of said substrate such that said main surface of said semiconductor pellet is faced to said first surface of said substrate and said binding pads are arranged in said slit in a plane view, said electrode pads including first electrode pads arranged at one side of said slit and second electrode pads arranged at the other side of said slit in said second direction;

(3) bonding wires electrically connecting said electrode pads of said substrate with said bonding pads of said semiconductor pellet via said slit, said bonding wires including first bonding wires connected to said first electrode pads and second bonding wires connected to said second electrode pads;

(4) bump electrodes being disposed on said second surface of said substrate and being electrically connected to said electrode pads of said substrate, said bump electrodes including first bump electrodes electrically connected to said first electrode pads and arranged at said one side of said slit and second bump electrodes electrically connected to said second electrode pads and arranged at the other side of said slit, said first and second bump electrodes being arranged to overlap with said semiconductor pellet in said plane view respectively; and

(5) a resin sealing body sealing said bonding wires and said main surface of said semiconductor pellet exposed from said slit.

97. (New) A semiconductor device according to claim 96, wherein said bonding pads are disposed at a substantially central area between said first pair of opposed edges of said semiconductor pellet.

98. (New) A semiconductor device according to claim 97, wherein said semiconductor pellet has a rectangular shape, and wherein said first pair of opposed edges are corresponding to a pair of longer edges and said second pair of opposed edges are corresponding to a pair of shorter edges.

99. (New) A semiconductor device according to claim 96, wherein said slit is tapered so that opening on said second surface of substrate is greater than opening on said first surface of said substrate.

100. (New) A semiconductor device according to claim 96, wherein said bump electrodes are formed of a Pb-Sn alloy.

101. (New) A semiconductor device according to claim 96, wherein at least some of said bonding pads extend in said first direction to form a row of bonding pads.